



# 20A, 45V - 200V Schottky Barrier Surface Mount Rectifier

#### **FEATURES**

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

#### **MECHANICAL DATA**

- Case: TO-263AB (D<sup>2</sup>PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F</sub>	20	Α	
$V_{RRM}$	45 - 200	V	
I <sub>FSM</sub>	150	Α	
T <sub>J MAX</sub>	150	°C	
Package	TO-263AB (D <sup>2</sup> PAK)		
Configuration	Dual dies		

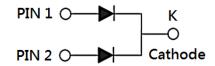








TO-263AB (D<sup>2</sup>PAK)



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)							
		MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	2045	2060	20100	20150	20200	UNIT
		CT-Y	CT-Y	CT-Y	CT-Y	CT-Y	
Marking code on the device		MBRS 2045CT	MBRS 2060CT	MBRS 20100CT	MBRS 20150CT	MBRS 20200CT	
Repetitive peak reverse voltage	$V_{RRM}$	45	60	100	150	200	V
Reverse voltage, total rms value	$V_{R(RMS)}$	31	42	70	105	140	V
Forward current	I <sub>F</sub>	20				Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	150				А	
Peak repetitive reverse surge current <sup>(1)</sup>	I <sub>RRM</sub>	1 0.5				Α	
Peak repetitive forward current (Rated V <sub>R</sub> , Square wave, 20KHz)	I <sub>FRM</sub>	20				Α	
Critical rate of rise of off-state voltage	dv/dt	10,000				V/µs	
Junction temperature	TJ	-55 to +150				°C	
Storage temperature	T <sub>STG</sub>	-55 to +150				°C	

1.  $tp = 2.0\mu s$ , 1.0KHz

THERMAL PERFORMANCE				
PARAMETER		SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	MBRS2045CT-Y MBRS2060CT-Y	R <sub>eJC</sub>	1.5	°C/W
Junction-to-case thermal resistance	MBRS20100CT-Y MBRS20150CT-Y MBRS20200CT-Y	R <sub>eJC</sub>	2	°C/W

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRS2045CT-Y	I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C		-	0.70	V
	MBRS2060CT-Y		,	-	0.80	V
	MBRS20100CT-Y			-	0.85	V
Forward voltage per	MBRS20150CT-Y MBRS20200CT-Y		V <sub>F</sub>	1	0.99	V
diode <sup>(1)</sup>	MBRS2045CT-Y			1	0.60	V
	MBRS2060CT-Y	I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C		-	0.70	V
	MBRS20100CT-Y			-	0.75	V
	MBRS20150CT-Y MBRS20200CT-Y			-	0.87	V
Doverse ourrent @	MBRS2045CT-Y MBRS2060CT-Y MBRS20100CT-Y MBRS20150CT-Y MBRS20200CT-Y	T <sub>J</sub> = 25°C		-	100	μΑ
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>	MBRS2045CT-Y		I <sub>R</sub>	-	15	mA
	MBRS2060CT-Y	T <sub>J</sub> = 125°C		-	10	mA
	MBRS20100CT-Y MBRS20150CT-Y MBRS20200CT-Y			-	5	mA

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE <sup>(1)</sup> PACKAGE PACKING				
MBRS20xCT-Y	TO-263AB (D <sup>2</sup> PAK)	800 / Tape & Reel		

#### Notes:

1. "x" defines voltage from 45V(MBRS2045CT-Y) to 200V(MBRS20200CT-Y)

Fig.2 Typical Junction Capacitance



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

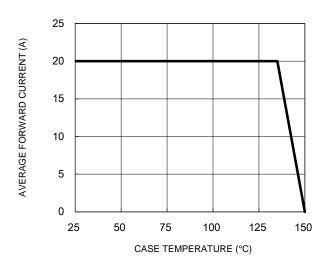


Fig.3 Typical Reverse Characteristics

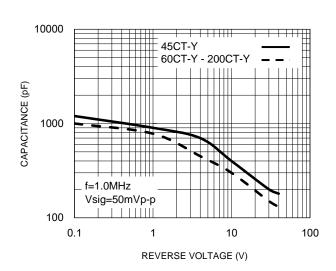
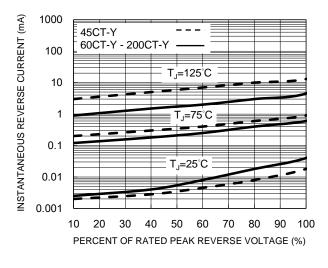


Fig.4 Typical Forward Characteristics



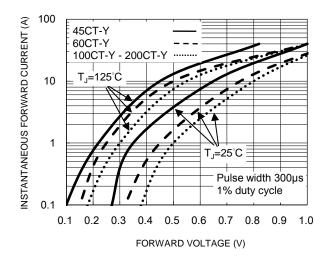
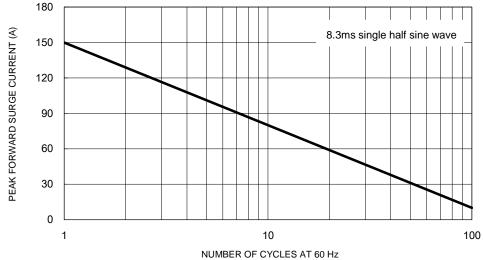


Fig.5 Maximum Non-Repetitive Forward Surge Current



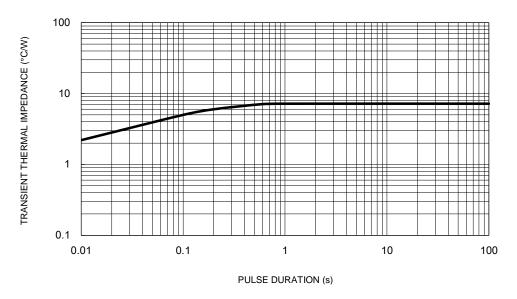
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### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.6 Typical Transient Thermal Impedance

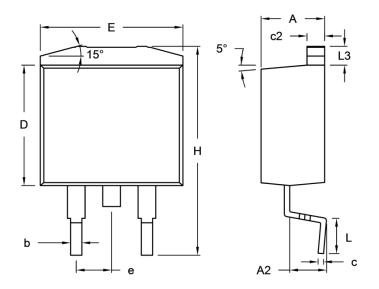




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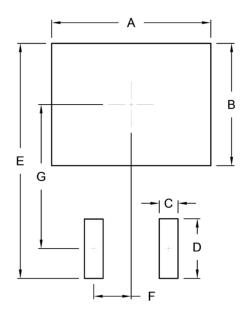
## **PACKAGE OUTLINE DIMENSIONS**

# TO-263AB (D<sup>2</sup>PAK)



DIM	DIM. Unit (mm)		Unit (inch)		
DIN.	Min.	Max.	Min.	Max.	
Α	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
С	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
Н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

### **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

### **MARKING DIAGRAM**



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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